

TOSHIBA Intelligent Power Module Silicon N Channel IGBT

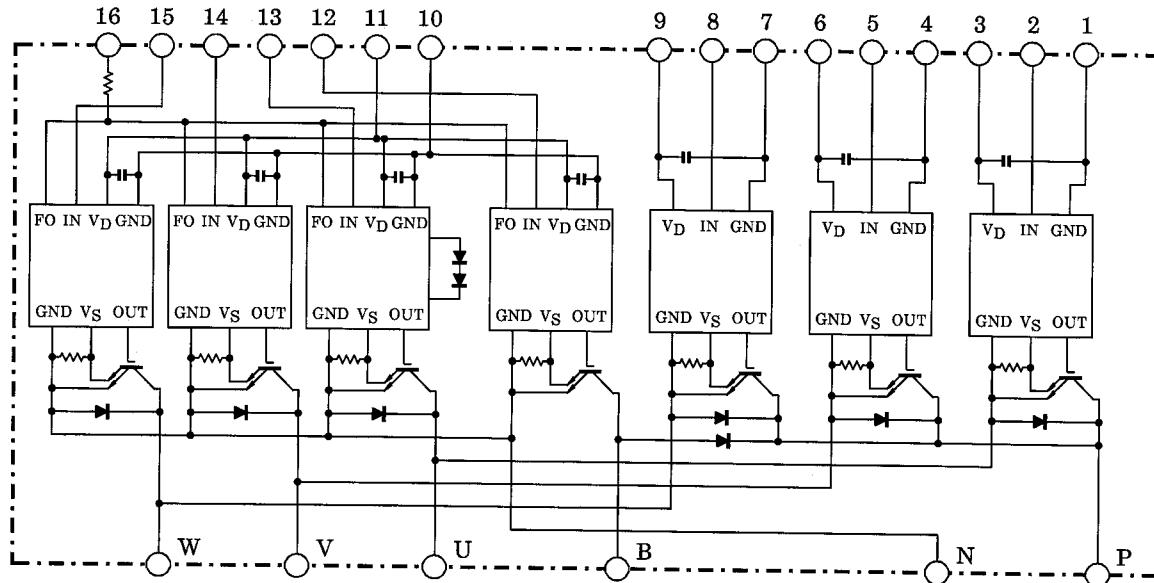
MIG100J201HC

High Power Switching Applications

Motor Control Applications

- Integrates inverter, brake power circuits & control circuits (IGBT drive units, protection units for over-current, under-voltage & over-temperature) in one package.
- The electrodes are isolated from case.
- High speed type IGBT : $V_{CE(\text{sat})} = 2.8 \text{ V (Max.)}$
 $t_{off} = 3.0 \mu\text{s (Max.)}$
 $t_{rr} = 0.30 \mu\text{s (Max.)}$
- Outline : TOSHIBA 2-110A1A
- Weight : 520 g

Equivalent Circuit



- | | | | | | |
|------------|------------|------------|-------------|------------|------------|
| 1. GND (U) | 2. IN (U) | 3. VD (U) | 4. GND (V) | 5. IN (V) | 6. VD (V) |
| 7. GND (W) | 8. IN (W) | 9. VD (W) | 10. GND (L) | 11. VD (L) | 12. IN (B) |
| 13. IN (X) | 14. IN (Y) | 15. IN (Z) | 16. FO | | |

Maximum Ratings ($T_j = 25^\circ\text{C}$)

Stage	Characteristic	Condition	Symbol	Ratings	Unit
Inverter	Supply voltage	P-N power terminal	V_{CC}	450	V
	Collector-emitter voltage	—	V_{CES}	600	V
	Collector current	$T_c = 25^\circ\text{C}$, DC	I_C	100	A
	Forward current	$T_c = 25^\circ\text{C}$, DC	I_F	100	A
	Collector power dissipation	$T_c = 25^\circ\text{C}$	P_C	300	W
	Junction temperature	—	T_j	150	$^\circ\text{C}$
Brake	Supply voltage	P-N power terminal	V_{CC}	450	V
	Collector-emitter voltage	—	V_{CES}	600	V
	Collector current	$T_c = 25^\circ\text{C}$, DC	I_C	30	A
	Reverse voltage	—	V_R	600	V
	Forward current	$T_c = 25^\circ\text{C}$, DC	I_F	30	A
	Collector power dissipation	$T_c = 25^\circ\text{C}$	P_C	80	W
	Junction temperature	—	T_j	150	$^\circ\text{C}$
Control	Control supply voltage	V_D -GND terminal	V_D	20	V
	Input voltage	IN-GND terminal	V_{IN}	20	V
	Fault output voltage	FO-GND (L) terminal	V_{FO}	20	V
	Fault output current	FO sink current	I_{FO}	14	mA
Module	Operating temperature	—	T_C	-20 ~ +100	$^\circ\text{C}$
	Storage temperature range	—	T_{stg}	-40 ~ +125	$^\circ\text{C}$
	Isolation voltage	AC 1 minute	V_{ISO}	2500	V
	Screw torque	M5	—	3	N·m

Electrical Characteristics ($T_j = 25^\circ\text{C}$)**a. Inverter Stage**

Characteristic	Symbol	Test Condition		Min	Typ.	Max	Unit
Collector cut-off current	I_{CEX}	$V_{CE} = 600 \text{ V}$	$T_j = 25^\circ\text{C}$	—	—	1	mA
			$T_j = 125^\circ\text{C}$	—	—	20	
Collector-emitter saturation voltage	$V_{CE} (\text{sat})$	$V_D = 15 \text{ V}$, $I_C = 100 \text{ A}$ $V_{IN} = 15 \text{ V} \rightarrow 0 \text{ V}$	$T_j = 25^\circ\text{C}$	—	2.3	2.8	V
			$T_j = 125^\circ\text{C}$	—	2.3	—	
Forward voltage	V_F	$I_F = 100 \text{ A}$	—	2.1	3.3	—	V
Switching time	t_{on}	$V_{CC} = 300 \text{ V}$, $I_C = 100 \text{ A}$ $V_D = 15 \text{ V}$, $V_{IN} = 15 \text{ V} \leftrightarrow 0 \text{ V}$ Inductive load (Note 1)	—	1.0	2.0	μs	
	t_{off}		—	1.7	3.0		
	t_f		—	0.2	0.5		
	t_{rr}		—	0.1	0.3		

b. Brake Stage

Characteristic	Symbol	Test Condition		Min	Typ.	Max	Unit
Collector cut-off current	I _{CEx}	V _{CEx} = 600V	T _j = 25°C	—	—	1	mA
			T _j = 125°C	—	—	20	
Collector-emitter saturation voltage	V _{CEx} (sat)	V _D = 15V, I _C = 30A V _{IN} = 15V → 0V	T _j = 25°C	—	1.7	2.7	V
			T _j = 125°C	—	1.6	—	
Reverse current	I _R	V _R =600V	T _j = 25°C	—	—	1	mA
			T _j = 125°C	—	—	20	
Forward voltage	V _F	I _F = 30A	—	2.0	2.5	V	
Switching time	t _{on}	V _{CC} = 300V, I _C = 30A V _D = 15V, V _{IN} = 15V → 0V Inductive load (Note 1)	—	0.9	2.0		μs
	t _{off}		—	1.7	3.0		
	t _f		—	0.25	0.5		
	t _{rr}		—	0.15	0.3		

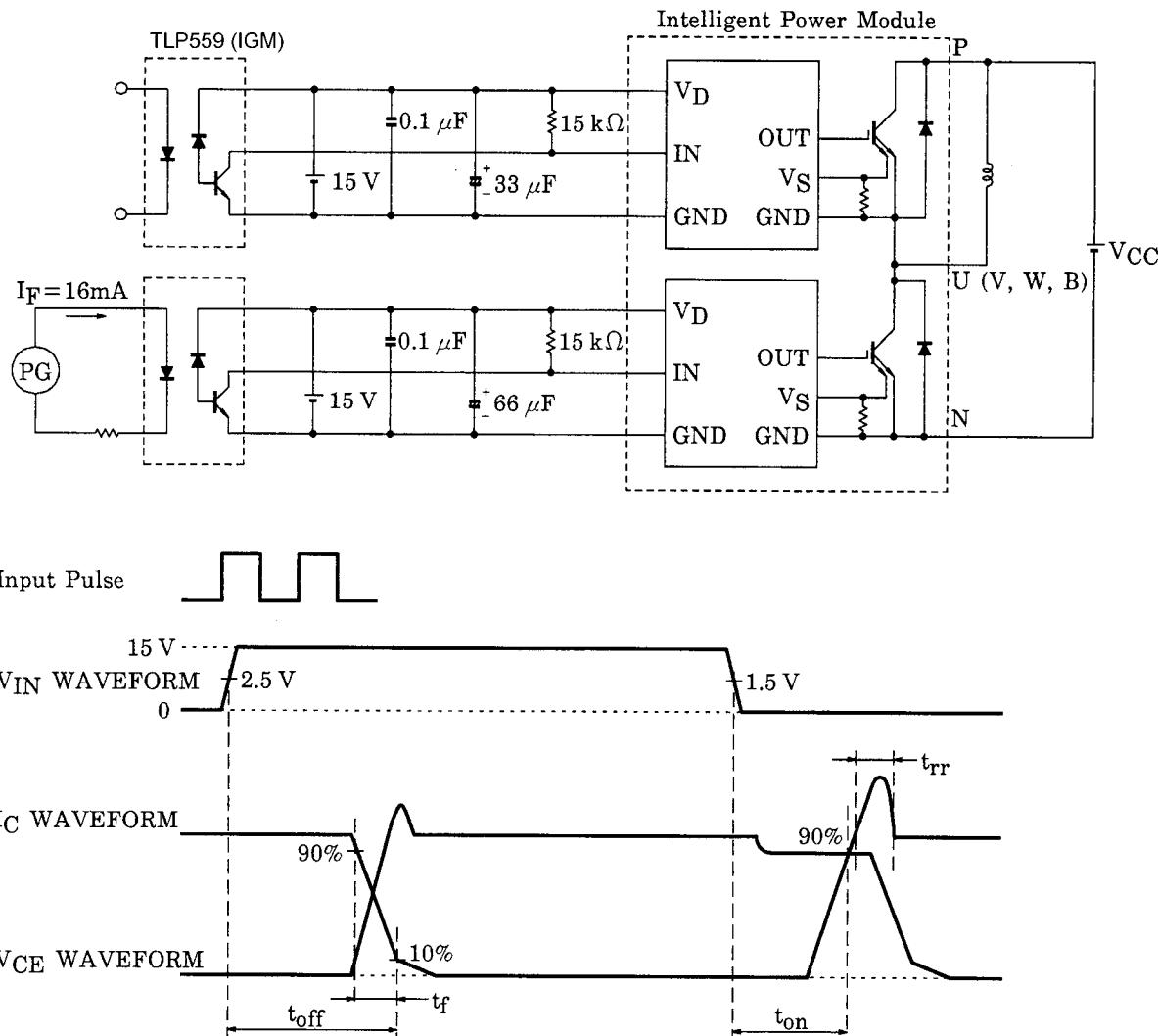
c. Control Stage (T_j = 25°C)

Characteristic	Symbol	Test Condition		Min	Typ.	Max	Unit
Control circuit current	High side	I _D (H)	V _D = 15 V	—	8	—	mA
	Low side	I _D (L)		—	35	—	
Input-on signal voltage	V _{IN} (on)	V _D = 15 V, I _C = 100 mA	—	1.3	1.5	1.7	V
Input-off signal voltage	V _{IN} (off)	V _D = 15 V, I _C = 100 mA	—	2.2	2.5	2.8	V
Fault output current	Protection	I _{FO} (on)	V _D = 15 V	8	10	12	mA
	Normal	I _{FO} (off)		—	—	1	
Over current protection trip level	Inverter	OC	V _D = 15 V, T _j = 125°C	160	200	—	A
	Brake			40	—	—	
Short current protection trip level	Trip level	SC	V _D = 15 V, T _j = 125°C	240	300	—	A
	Reset level			60	—	—	
Over current cut-off time	t _{off} (OC)	V _D = 15 V	—	5	—	μs	
Over temperature protection	Trip level	OT	Case temperature	110	118	125	°C
	Reset level	OTr		—	80	—	
Control supply under voltage protection	Trip level	UV	—	11.0	12.0	12.5	V
	Reset level	UVr		—	12.5	—	
Fault output pulse width	t _{FO}	V _D = 15 V	—	1	2	3	ms

d. Thermal Resistance ($T_j = 25^\circ\text{C}$)

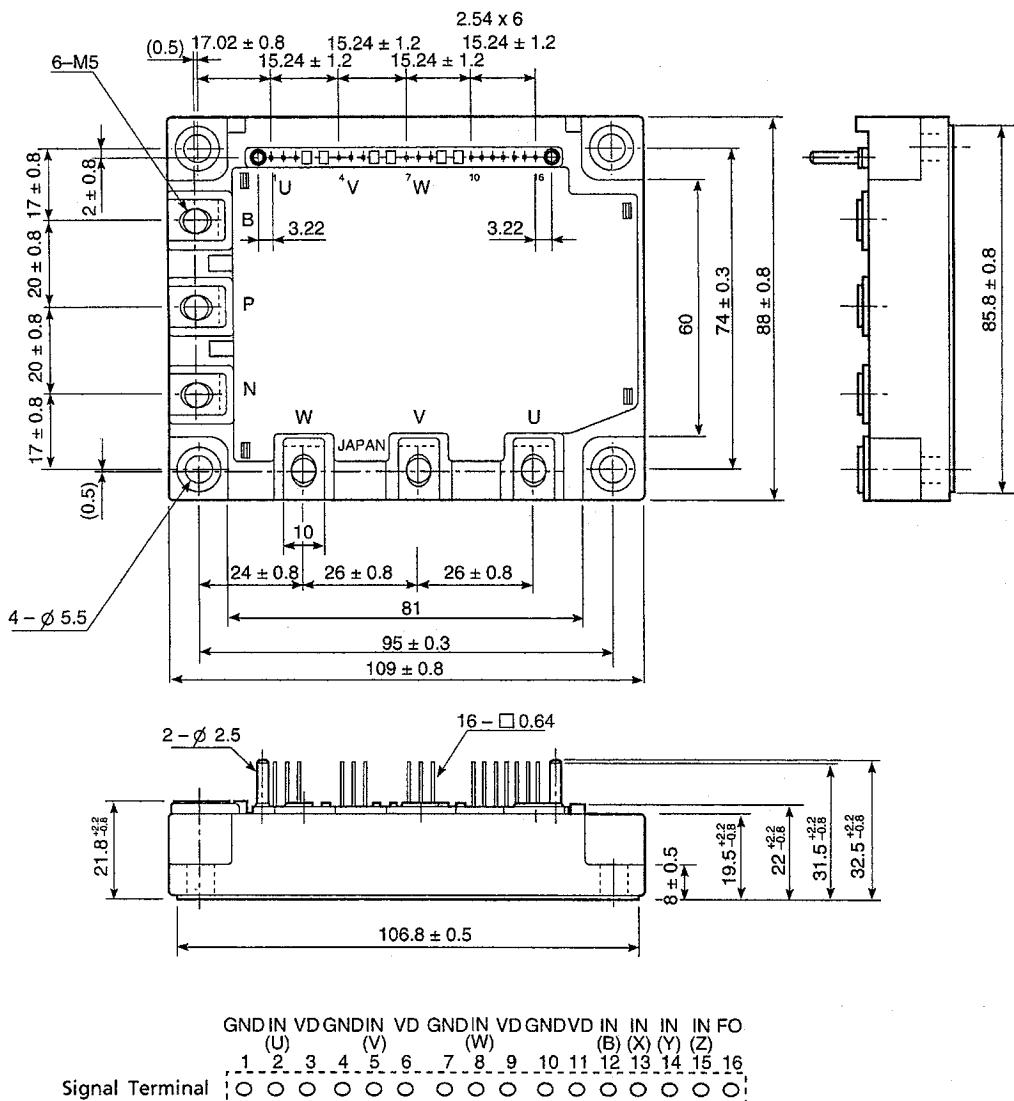
Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Junction to case thermal resistance	$R_{th}(j-c)$	Inverter IGBT stage	—	—	0.418	$^\circ\text{C} / \text{W}$
		Inverter FRD stage	—	—	1.000	
		Brake IGBT stage	—	—	1.562	
		Brake FRD stage	—	—	2.000	
Case to fin thermal resistance	$R_{th}(c-f)$	Compound is applied	—	0.05	—	$^\circ\text{C} / \text{W}$

Note 1: Switching time test circuit & timing chart



Package Dimensions: TOSHIBA 2-110A1A

Unit: mm



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